

The documentation and process conversion measures necessary to comply with this revision shall be completed by 14 March 2007.

INCH-POUND

MIL-PRF-19500/441J  
 14 November 2006  
 SUPERSEDING  
 MIL-PRF-19500/441H  
 2 September 2003

\* PERFORMANCE SPECIFICATION SHEET

SEMICONDUCTOR DEVICE, TRANSISTOR, PNP, SILICON, POWER,  
 TYPES 2N3740, 2N3740U4, 2N3741, AND 2N3741U4,  
 JAN, JANTX, JANTXV, JANS, JANHC, AND JANKC

This specification is approved for use by all Departments  
 and Agencies of the Department of Defense.

\* The requirements for acquiring the product described herein shall consist of this specification sheet and MIL-PRF-19500.

1. SCOPE

1.1 Scope. This specification covers the performance requirements for PNP, silicon, power transistors. Four levels of product assurance are provided for each encapsulated device type as specified in MIL-PRF-19500, and two levels of product assurance for each unencapsulated device type die.

\* 1.2 Physical dimensions. See figure 1, TO-66, figure 2 (U4, surface mount) for encapsulated devices, and figures 3 and 4 for unencapsulated devices (JANHC and JANKC).

\* 1.3 Maximum ratings. Unless otherwise specified,  $T_A = +25^\circ\text{C}$ .

Types	$P_T$ (1)		$R_{\theta JC}$ (2) TO-66 only	$R_{\theta JC}$ (2) U4 only	$V_{CBO}$	$V_{CEO}$	$V_{EBO}$	$I_B$	$I_C$	$T_{STG}$ and $T_J$
	$T_C = +25^\circ\text{C}$	$T_C = +100^\circ\text{C}$								
	<u>W</u>	<u>W</u>	<u><math>^\circ\text{C/W}</math></u>	<u><math>^\circ\text{C/W}</math></u>	<u>V dc</u>	<u>V dc</u>	<u>V dc</u>	<u>A dc</u>	<u>A dc</u>	<u><math>^\circ\text{C}</math></u>
2N3740, 2N3740U4	25	14	7	6	60	60	7	2	4	-65 to +200
2N3741, 2N3741U4	25	14	7	6	80	80	7	2	4	-65 to +200

(1) See figures 5 and 6 for temperature-power derating curves.

(2) See figures 7 and 8, transient thermal impedance graphs.

\* Comments, suggestions, or questions on this document should be addressed to Defense Supply Center, Columbus, ATTN: DSCC-VAC, P.O. Box 3990, Columbus, OH 43218-3990, or emailed to [Semiconductor@dsc.dla.mil](mailto:Semiconductor@dsc.dla.mil). Since contact information can change, you may want to verify the currency of this address information using the ASSIST Online database at <http://assist.daps.dla.mil/>.

1.4 Primary electrical characteristics at  $T_C = +25^\circ\text{C}$ .

Limits	$h_{FE2}$ (1) $V_{CE} = 1 \text{ V dc}$ $I_C = 250 \text{ mA dc}$	$h_{FE4}$ (1) $V_{CE} = 1 \text{ V dc}$ $I_C = 1 \text{ A dc}$	$ h_{FE} $ $V_{CE} = 10 \text{ V dc}$ $I_C = 100 \text{ mA dc}$ $f = 5 \text{ MHz}$	$V_{CE(sat)}^2$ (1) $I_C = 1.0 \text{ A dc}$ $I_B = 125 \text{ mA dc}$	$C_{obo}$ $V_{CB} = 10 \text{ V dc}$ $I_E = 0$ $100 \text{ kHz} \leq f \leq 1 \text{ MHz}$	Pulse response	
						$t_{on}$	$t_{off}$
Min	30	10	1	<u>V dc</u>	<u>pF</u>	<u>ns</u>	<u>μs</u>
Max	120		12	0.6	100	400	1

(1) Pulsed (see 4.5.1).

## 2. APPLICABLE DOCUMENTS

\* 2.1 General. The documents listed in this section are specified in sections 3, 4, or 5 of this specification. This section does not include documents cited in other sections of this specification or recommended for additional information or as examples. While every effort has been made to ensure the completeness of this list, document users are cautioned that they must meet all specified requirements of documents cited in sections 3, 4, or 5 of this specification, whether or not they are listed.

2.2 Government documents.

\* 2.2.1 Specifications, standards, and handbooks. The following specifications, standards, and handbooks form a part of this document to the extent specified herein. Unless otherwise specified, the issues of these documents are those cited in the solicitation or contract.

## \* DEPARTMENT OF DEFENSE SPECIFICATIONS

MIL-PRF-19500 - Semiconductor Devices, General Specification for.

## \* DEPARTMENT OF DEFENSE STANDARDS

MIL-STD-750 - Test Methods for Semiconductor Devices.

\* (Copies of these documents are available online at <http://assist.daps.dla.mil/quicksearch/> or <http://assist.daps.dla.mil/> or from the Standardization Document Order Desk, 700 Robbins Avenue, Building 4D, Philadelphia, PA 19111-5094.)

2.3 Order of precedence. In the event of a conflict between the text of this document and the references cited herein, the text of this document takes precedence. Nothing in this document, however, supersedes applicable laws and regulations unless a specific exemption has been obtained.

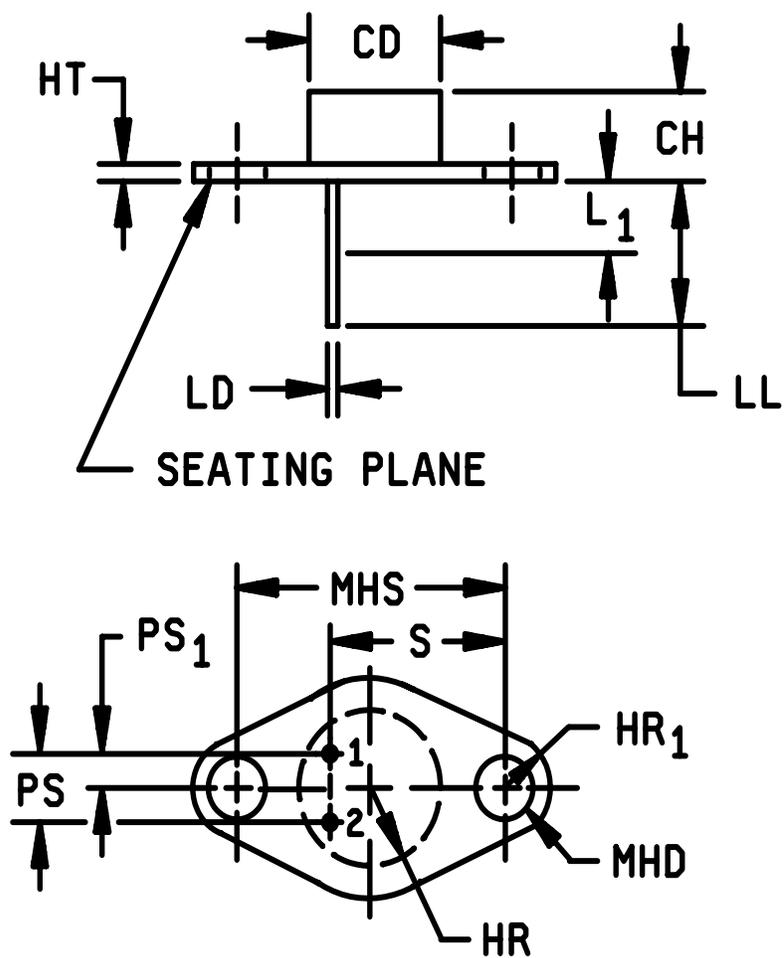
## 3. REQUIREMENTS

3.1 General. The individual item requirements shall be as specified in MIL-PRF-19500 and as modified herein.

3.2 Qualification. Devices furnished under this specification shall be products that are manufactured by a manufacturer authorized by the qualifying activity for listing on the applicable qualified manufacturers' list (QML) before contract award (see 4.2 and 6.3).

3.3 Abbreviations, symbols, and definitions. Abbreviations, symbols, and definitions used herein shall be as specified in MIL-PRF-19500.

\* 3.4 Interface and physical dimensions. Interface and physical dimensions shall be as specified in MIL-PRF-19500, and on figures 1 (TO-66), 2 (surface mount, U4), 3, and 4 (die).



\* FIGURE 1. Physical dimensions, TO-66 (2N3740, 2N3741).

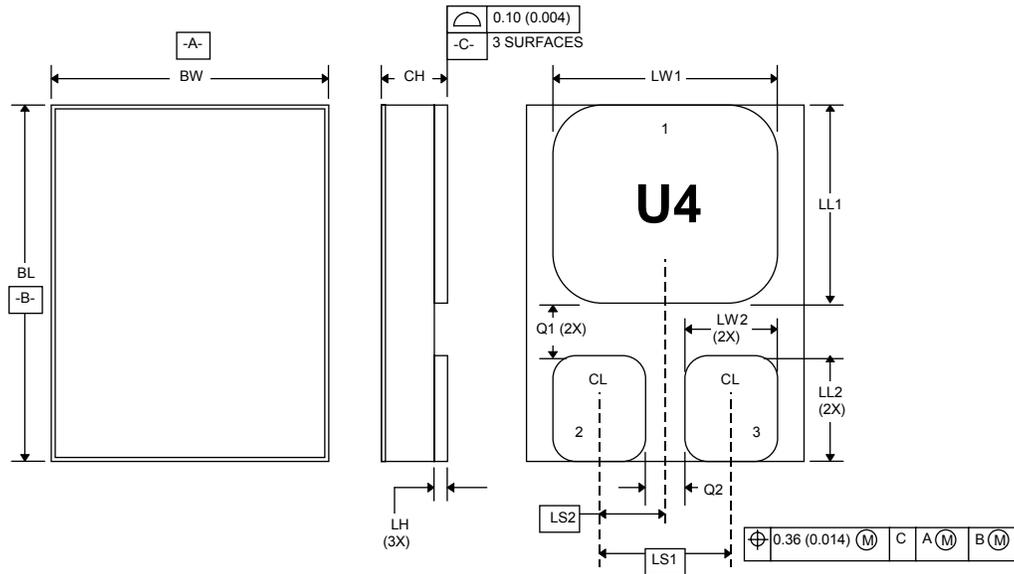
Symbol	Dimensions				Notes	Symbol	Dimensions				Notes
	Inches		Millimeter				Inches		Millimeters		
	Min	Max	Min	Max			Min	Max	Min	Max	
CD		.620		15.75	9	LL	.360	.500	9.14	12.70	4, 8
CH	.250	.340	6.35	8.64		L <sub>1</sub>		.050		1.27	4, 8
HT	.050	.075	1.27	1.91		MHD	.142	.152	3.61	3.86	6, 9
HR		.350		8.89		MHS	.958	.962	24.33	24.43	
HR <sub>1</sub>	.115	.145	2.92	3.68	5	PS	.190	.210	4.83	5.33	3
LD	.028	.034	0.71	0.86	4, 8, 9	PS <sub>1</sub>	.093	.107	2.36	2.72	3
						S	.570	.590	14.48	14.99	3

## NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. These dimensions should be measured at points .050 to .055 inch (1.27 to 1.40 mm) below seating plane. When gauge is not used, measurement will be made at seating plane.
4. Both terminals.
5. At both ends.
6. Two holes.
7. The collector shall be electrically connected to the case.
- \* 8. LD applies between L<sub>1</sub> and LL. Lead diameter shall not exceed twice LD within L<sub>1</sub>.
9. In accordance with ASME Y14.5M, diameters are equivalent to  $\phi$  symbology.
10. Lead 1 is the emitter, lead 2 is the base, collector is the case.

\* FIGURE 1. Physical dimensions, TO-66 (2N3740, 2N3741) - Continued.

MIL-PRF-19500/441J

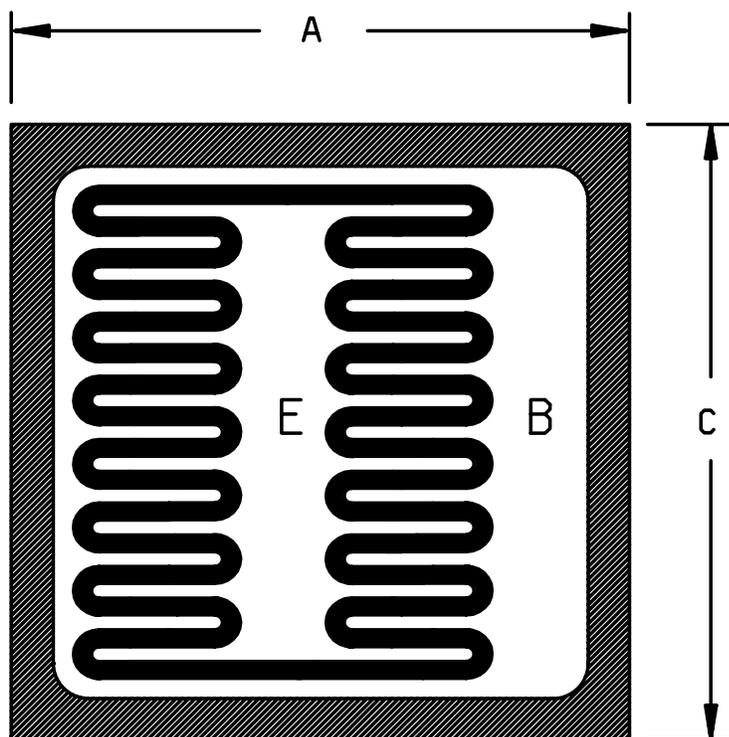


Symbol	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
BL	.215	.225	5.46	5.72
BW	.145	.155	3.68	3.94
CH	.050	.070	1.27	1.77
LH		.020		0.50
LW1	.135	.145	3.43	3.68
LW2	.047	.057	1.19	1.45
LL1	.085	.125	2.16	3.17
LL2	.045	.075	1.14	1.91
LS1	.065	.095	1.65	2.41
LS2	.033	.048	0.838	1.21
Q1	.045	.070	1.14	1.78
Q2	.025	.048	0.635	1.22
TERM 1	Collector			
TERM 2	Base			
TERM 3	Emitter			

NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. Dimensions and tolerances shall be in accordance with ASME Y14.5M.

FIGURE 2. Physical dimensions and configuration (SMD.22) (2N3740U4, 2N3741U4).



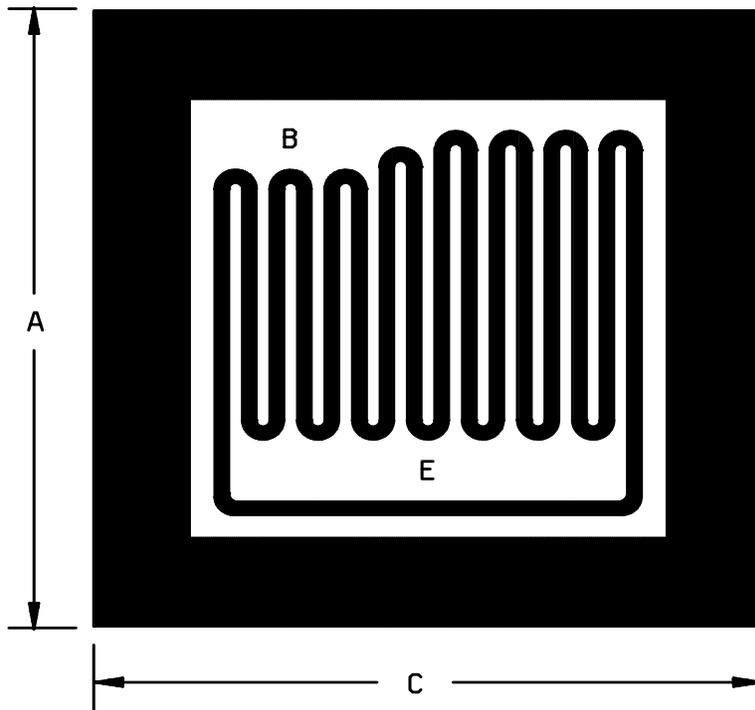
A - version

Ltr	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
A	.059	.069	1.49	1.76
C	.059	.069	1.49	1.76

## NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. The physical characteristics of the die are:  
 Thickness: .008 inch (0.20 mm) to .012 inch (0.30 mm).  
 Top metal: Aluminum 25,000 Å minimum, 30,000 Å nominal.  
 Back metal: Gold 2,500 Å minimum, 3,000 Å nominal.  
 Back side: Collector.  
 Bonding pad:  
   B = .045 inch (1.14 mm) x .0075 inch (0.19 mm).  
   E = .039 inch (0.99 mm) x .0075 inch (0.19 mm).
4. Element evaluation shall be performed on case outline TO-66.
5. Dimensions and tolerances shall be in accordance with ASME Y14.5M.

\* FIGURE 3. Physical dimensions, JANHCA and JANKCA die.



B - version

Ltr	Dimensions			
	Inches		Millimeters	
	Min	Max	Min	Max
A	.083	.087	2.11	2.21
C	.083	.087	2.11	2.21

NOTES:

1. Dimensions are in inches.
2. Millimeters are given for general information only.
3. The physical characteristics of the die are:  
 Thickness: .014 inch (0.36 mm) to .018 inch (0.46 mm).  
 Top metal: Aluminum 20,000 Å minimum, 30,000 Å nominal 50,000 Å maximum.  
 Back metal: T1 = 5,000 Å nominal  $\pm 2,000$  Å; N1 = 10,000 Å nominal  $\pm 2,000$  Å;  
 AG = 10,000 Å nominal  $\pm 2,000$  Å.  
 Back side: Collector.  
 Bonding pad: B = .021 inch (0.53 mm) x .008 inch (0.20 mm)  $\pm .002$  inch (0.05 mm).  
 E = .040 inch (1.01 mm) x .008 inch (0.20 mm)  $\pm .002$  inch (0.05 mm).
4. Element evaluation shall be performed on case outline TO-66.
5. Dimensions and tolerances shall be in accordance with ASME Y14.5M.

\* FIGURE 4. Physical dimensions, JANHCB and JANKCB die.

3.4.1 Lead finish. Unless otherwise specified, lead finish shall be solderable in accordance with MIL-PRF-19500, MIL-STD-750, and herein. Where a choice of lead finish is desired, it shall be specified in the acquisition document (see 6.2).

3.5 Electrical performance characteristics. Unless otherwise specified herein, the electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.6 Electrical test requirements. The electrical test requirements shall be the subgroups specified in table I herein.

3.7 Marking. Marking shall be in accordance with MIL-PRF-19500.

3.8 Workmanship. Semiconductor devices shall be processed in such a manner as to be uniform in quality and shall be free from other defects that will affect life, serviceability, or appearance.

#### 4. VERIFICATION

4.1 Classification of inspections. The inspection requirements specified herein are classified as follows:

- a. Qualification inspection (see 4.2).
- b. Screening (see 4.3).
- \* c. Conformance inspection (see 4.4 and table I and II).

4.2 Qualification inspection. Qualification inspection shall be in accordance with MIL-PRF-19500 and as specified herein.

4.2.1 JANHC and JANKC devices. JANHC and JANKC devices are qualified in accordance with MIL-PRF-19500, appendix G.

\* 4.2.2 Group E qualification. Group E inspection shall be performed for qualification or re-qualification only. In case qualification was awarded to a prior revision of the specification sheet that did not request the performance of table III tests, the tests specified in table III herein that were not performed in the prior revision shall be performed on the first inspection lot of this revision to maintain qualification.

\* 4.3 Screening (JANS, JANTXV, and JANTX levels only). Screening shall be in accordance with table E-IV of MIL-PRF-19500, and as specified herein. The following measurements shall be made in accordance with table I herein. Devices that exceed the limits of table I herein shall not be acceptable.

Screen (see table E-IV of MIL-PRF-19500)	Measurement	
	JANS level	JANTX and JANTXV levels
(1) 3c	Thermal impedance, method 3131 of MIL-STD-750, see 4.3.3.	Thermal impedance, method 3131 of MIL-STD-750, see 4.3.3.
9	$I_{CEX1}$ and $h_{FE2}$	Not applicable
10	48 hours minimum	48 hours minimum
11	$I_{CEX1}$ and $h_{FE2}$ ; $\Delta I_{CEX1}$ = 100 percent of initial value or 50 nA dc, whichever is greater, $\Delta h_{FE2}$ = $\pm$ 25 percent of initial value.	$I_{CEX1}$ and $h_{FE2}$
12	See 4.3.1	See 4.3.1
13	Subgroups 2 and 3 of table I herein; $\Delta I_{CEX1}$ = 100 percent of initial value or 50 nA dc; whichever is greater; $\Delta h_{FE2}$ = $\pm$ 25 percent of initial value.	Subgroup 2 of table I herein; $\Delta I_{CEX1}$ = 100 percent of initial value or 50 nA dc, whichever is greater; $\Delta h_{FE2}$ = $\pm$ 25 percent of initial value.

(1) Thermal impedance shall be performed anytime after temperature cycling, screen 3a and does not need to be repeated in screening requirements.

4.3.1 Power burn-in conditions. Power burn-in conditions are as follows:  $V_{CB}$  = 10 - 30 V dc. Power shall be applied to the device to achieve a junction temperature,  $T_J$  = +175 °C minimum and a minimum  $P_D$  = 75 percent of  $P_T$  maximum rated as defined in 1.3.

\* 4.3.2 Screening (JANHC and JANKC). Screening of JANHC and JANKC die shall be in accordance with appendix G of MIL-PRF-19500. Burn-in duration for the JANKC level follows JANS requirements; the JANHC follows JANTX requirements.

\* 4.3.3 Thermal impedance. The thermal impedance measurements shall be performed in accordance with method 3131 of MIL-STD-750 using the guidelines in that method for determining  $I_M$ ,  $I_H$ ,  $t_H$ ,  $t_{SW}$ , (and  $V_H$  where appropriate). Measurement delay time ( $t_{MD}$ ) = 70  $\mu$ s max. See table III, group E, subgroup 4 herein.

4.4 Conformance inspection. Conformance inspection shall be in accordance with MIL-PRF-19500 and as specified herein.

4.4.1 Group A inspection. Group A inspection shall be conducted in accordance with table E-V of MIL-PRF-19500, and table I herein. End-point electrical measurements shall be in accordance with table I, subgroup 2 herein.

\* 4.4.2 Group B inspection. Group B inspection shall be conducted in accordance with the conditions specified for subgroup testing in table E-VIA (JANS) of MIL-PRF-19500 and 4.4.2.1 herein. Electrical measurements (end-points) requirements for JANS shall be in accordance with table I, subgroup 2 herein. Delta requirements shall be in accordance with table II herein. See 4.4.2.2 herein for JAN, JANTX, and JANTXV group B testing. Electrical measurements (end-points) and delta requirements for JAN, JANTX, and JANTXV shall be after each step in 4.4.2.2 and shall be in accordance with table I, subgroup 2 and table II herein.

4.4.2.1 Group B inspection, table E-VIA (JANS) of MIL-PRF-19500.

<u>Subgroup</u>	<u>Method</u>	<u>Conditions</u>
* B4	1037	$V_{CB} = 10$ V dc, 2,000 cycles, $t_{ON} = t_{OFF} = 3$ minutes, $P_{D(ON)} = P_D$ max rated in accordance with 1.3; $P_{D(OFF)} = 0$ .
B5	1027	(NOTE: If a failure occurs, resubmission shall be at the test conditions of the original sample.) $V_{CB} = 10$ V dc, $P_D \geq 100$ percent of maximum rated $P_T$ (see 1.3).  Option 1: 96 hours minimum sample size in accordance with table VIa of MIL-PRF-19500, adjust $T_A$ or $P_D$ to achieve $T_J = +275^\circ\text{C}$ minimum.  Option 2: 216 hours minimum, sample size = 45, $c = 0$ ; adjust $T_A$ or $P_D$ to achieve $T_J = +225^\circ\text{C}$ minimum.

4.4.2.2 Group B inspection, (JAN, JANTX and JANTXV) herein. Separate samples may be used for each step. In the event of a group B failure, the manufacturer may pull a new sample at double size from either the failed assembly lot or from another assembly lot from the same wafer lot. If the new "assembly lot" option is exercised, the failed assembly lot shall be scrapped.

<u>Step</u>	<u>Method</u>	<u>Condition</u>
* 1	1037	6,000 cycles, $t_{ON} = t_{OFF} = 3$ minutes, $P_{D(ON)} = P_D$ max rated per 1.3; $P_{D(OFF)} = 0$ . $n = 45$ , $c = 0$ .
* 2	1048	Blocking life: $T_A = +150^\circ\text{C}$ , $V_{CB} = 80$ percent of rated voltage, 48 hours min. $n = 45$ , $c = 0$ .
3	1032	High-temperature life (non-operating), $t = 340$ hours, $T_A = +200^\circ\text{C}$ . $n = 22$ , $c = 0$ .

4.4.2.3 Group B sample selection. Samples selected from group B inspection shall meet all of the following requirements:

- For JAN, JANTX, and JANTXV, samples shall be selected randomly from a minimum of three wafers (or from each wafer in the lot) from each wafer lot. For JANS, samples shall be selected from each inspection lot. See MIL-PRF-19500.
- Shall be chosen from an inspection lot that has been submitted to and passed table I, subgroup 2, conformance inspection. When the final lead finish is solder or any plating prone to oxidation at high temperature, the samples for life test (subgroups B4 and B5 for JANS, and group B for JAN, JANTX, and JANTXV) may be pulled prior to the application of final lead finish.

\* 4.4.3 Group C inspection. Group C inspection shall be conducted in accordance with the conditions specified for subgroup testing in table E-VII of MIL-PRF-19500, and 4.4.3.1 (JANS), and 4.4.3.2 (JAN, JANTX, and JANTXV) herein for group C testing. Electrical measurements (end-points) shall be as specified in table I, subgroup 2. Delta requirements shall be in accordance with table II herein.

4.4.3.1 Group C inspection, table E-VII (JANS only) of MIL-PRF-19500.

	<u>Subgroup</u>	<u>Method</u>	<u>Conditions</u>
*	C2	2036	Test condition A, weight = 3 lbs, t = 15 s, not applicable to 2N3740U4 and 2N3741U4.
*	C5	3131	Thermal resistance; see 4.3.3, $R_{\theta JC} = 7^{\circ}\text{C/W}$ for 2N3740, 2N3741; $R_{\theta JC} = 6^{\circ}\text{C/W}$ for 2N3740U4, 2N3741U4.
*	C6	1037	6,000 cycles, $t_{\text{ON}} = t_{\text{OFF}} = 3$ minutes, $P_{\text{D(ON)}} = P_{\text{D}}$ max rated in accordance with 1.3; $P_{\text{D(OFF)}} = 0$ .

\* 4.4.3.2 Group C inspection, table E-VII (JAN, JANTX, and JANTXV only) of MIL-PRF-19500.

	<u>Subgroup</u>	<u>Method</u>	<u>Conditions</u>
*	C2	2036	Test condition A, weight = 3 lbs, t = 15 s, not applicable to 2N3740U4 and 2N3741U4.
*	C5	3131	Thermal resistance; see 4.3.3, $R_{\theta JC} = 7^{\circ}\text{C/W}$ for 2N3740, 2N3741; $R_{\theta JC} = 6^{\circ}\text{C/W}$ for 2N3740U4, 2N3741U4.
	C6		Not applicable.

4.4.3.3 Group C inspection sample selection. Samples for subgroups in group C shall be chosen at random from any lot containing the intended package type and lead finish procured to the same specification which is submitted to and passes table I tests for conformance inspection. Testing of a group using a single device type enclosed in the intended package type shall be considered as complying with the requirements for that subgroup.

\* 4.4.4 Group E inspection. Group E inspection shall be conducted in accordance with the conditions specified for subgroup testing in table E-IX of MIL-PRF-19500 and as specified herein. Electrical measurements (end-points) shall be in accordance with the applicable steps of table I, subgroup 2. Delta requirements shall be in accordance with table II herein.

4.5 Methods of inspection. Methods of inspection shall be as specified in the appropriate tables and as follows.

4.5.1 Pulse measurements. Conditions for pulse measurement shall be as specified in section 4 of MIL-STD-750.

4.5.2 Inspection conditions. Unless otherwise specified, all inspections shall be conducted at a case temperature of  $+25^{\circ}\text{C} \pm 3^{\circ}\text{C}$ .

MIL-PRF-19500/441J

\* TABLE I. Group A inspection.

Inspection <u>1/</u>	MIL-STD-750		Symbol	Limits		Unit
	Method	Conditions		Min	Max	
<u>Subgroup 1 2/</u>						
Visual and mechanical <u>3/</u> examination	2071	n = 45 devices, c = 0				
Solderability <u>3/ 4/</u>	2026	n = 15 leads, c = 0				
Resistance to <u>3/ 4/ 5/</u> solvent	1022	n = 15 devices, c = 0				
Temp cycling <u>3/ 4/</u>	1051	Test condition C, 25 cycles. n = 22 devices, c = 0				
Hermetic seal <u>4/</u>	1071	n = 22 devices, c = 0				
Fine leak Gross leak						
Electrical measurements <u>4/</u>		Table I, subgroup 2 herein				
Bond strength <u>3/ 4/</u>	2037	Precondition T <sub>A</sub> = +250°C at t = 24 hrs or T <sub>A</sub> = +300°C at t = 2 hrs, n = 11 wires, c = 0				
<u>Subgroup 2</u>						
* Thermal impedance <u>6/</u>	3131	See 4.3.3	Z <sub>θJX</sub>			°C/W
Breakdown voltage, collector to emitter 2N3740, 2N3740U4 2N3741, 2N3741U4	3011	Bias condition D; I <sub>C</sub> = 100 mA dc; pulsed (see 4.5.1)	V <sub>(BR)CEO</sub>	60 80		V dc V dc
Collector to emitter cutoff current 2N3740, 2N3740U4 2N3741, 2N3741U4	3041	Bias condition D  V <sub>CE</sub> = 40 V dc V <sub>CE</sub> = 60 V dc	I <sub>CEO</sub>		10	μA dc
Emitter to base cutoff current	3061	Bias condition D; V <sub>EB</sub> = 7 V dc	I <sub>EBO</sub>		100	nA dc
Collector to emitter cutoff current 2N3740, 2N3740U4 2N3741, 2N3741U4	3041	Bias condition A; V <sub>BE</sub> = 1.5 V dc  V <sub>CE</sub> = 60 V dc V <sub>CE</sub> = 80 V dc	I <sub>CEX1</sub>		300	nA dc
Collector to base cutoff current 2N3740, 2N3740U4 2N3741, 2N3741U4	3036	Bias condition D  V <sub>CE</sub> = 60 V dc V <sub>CE</sub> = 80 V dc	I <sub>CBO</sub>		100	nA dc

See footnotes at end of table.

\* TABLE I. Group A inspection - Continued.

Inspection 1/	MIL-STD-750		Symbol	Limits		Unit
	Method	Conditions		Min	Max	
<u>Subgroup 2</u> -Continued.						
Base emitter voltage (nonsaturated)	3066	Test condition B; $V_{CE} = 1$ V dc; $I_C = 250$ mA dc pulsed (see 4.5.1)	$V_{BE}$		1	V dc
Saturation voltage and resistance	3071	$I_C = 250$ mA dc; $I_B = 25$ mA dc pulsed (see 4.5.1)	$V_{CE(sat)1}$		0.4	V dc
Saturation voltage and resistance	3071	$I_C = 1$ A dc; $I_B = 125$ mA dc pulsed (see 4.5.1)	$V_{CE(sat)2}$		0.6	V dc
Forward-current transfer ratio	3076	$V_{CE} = 1$ V dc; pulsed (see 4.5.1)				
		$I_C = 100$ mA dc	$h_{FE1}$	40		
		$I_C = 250$ mA dc	$h_{FE2}$	30	120	
		$I_C = 500$ mA dc	$h_{FE3}$	20		
		$I_C = 1$ A dc	$h_{FE4}$	10		
Forward-current transfer ratio	3076	$V_{CE} = 5$ V dc; $I_C = 4$ A dc pulsed (see 4.5.1)	$h_{FE5}$	3		
<u>Subgroup 3</u>						
High temperature operation:		$T_A = +150^\circ\text{C}$				
Collector to emitter cutoff current 2N3740, 2N3740U4 2N3741, 2N3741U4	3041	Bias condition A, $V_{BE} = 1.5$ V dc $V_{CE} = 60$ V dc $V_{CE} = 80$ V dc	$I_{CEX2}$		25	$\mu\text{A}$ dc
Low temperature operation:		$T_A = -55^\circ\text{C}$				
Forward-current transfer ratio	3076	$V_{CE} = 1$ V dc; $I_C = 250$ mA dc pulsed (see 4.5.1)	$h_{FE6}$	10		
<u>Subgroup 4</u>						
Small-signal short-circuit forward-current transfer ratio	3206	$V_{CE} = 10$ V dc; $I_C = 50$ mA dc; $f = 1$ kHz	$h_{fe}$	25	250	
Small-signal short-circuit forward-current transfer ratio	3306	$V_{CE} = 10$ V dc; $I_C = 100$ mA dc; $f = 5$ MHz	$ h_{fe} $	1	12	
Open circuit output capacitance	3236	$V_{CB} = 10$ V dc; $I_E = 0$ ; $100$ KHz $\leq f \leq 1$ MHz	$C_{obo}$		100	pF

See footnotes at end of table.

\* TABLE I. Group A inspection - Continued.

Inspection <u>1</u> /	MIL-STD-750		Symbol	Limits		Unit
	Method	Conditions		Min	Max	
<u>Subgroup 4</u> - Continued.						
Pulse response						
Turn-on time		$I_C = 1 \text{ A dc}; I_{B1} = 0.1 \text{ A dc}$ (see figure 9)	$t_{on}$	400		ns
Turn-off time		$I_C = 1 \text{ A dc}; I_{B1} = I_{B2} = 0.1 \text{ A dc}$ (see figure 9)	$t_{off}$	1		$\mu\text{s}$
<u>Subgroup 5</u>						
SOA (continuous dc)	3051	$T_C = +25^\circ\text{C}$ ; power application time = 1 s; 1 cycle (see figure 10)				
Test 1		$V_{CE} = 6.25 \text{ V dc}; I_C = 4 \text{ A dc}$				
Test 2		$V_{CE} = 20 \text{ V dc}; I_C = 1.25 \text{ A dc}$				
Test 3		$I_C = 150 \text{ mA dc}$				
2N3740, 2N3740U4 2N3741, 2N3741U4		$V_{CE} = 50 \text{ V dc}$ $V_{CE} = 65 \text{ V dc}$				
SOA (clamped switching)		$T_A = +25^\circ\text{C}; V_{CC} = 15 \text{ V dc}$ ; duty cycle $\leq 5$ percent, $t_p = 1.5 \text{ ms}$ (vary to obtain $I_C$ ), $I_C = 4 \text{ A dc}$ (see figures 11 and 12)				
2N3740 2N3741		Clamp voltage = 60 V dc Clamp voltage = 80 V dc				
End-point electrical measurements		See table I, subgroup 2 herein.				
SOA (switching)	3053	Load condition C (unclamped inductive) (see figure 13); $T_A = +25^\circ\text{C}$ ; duty cycle $\leq 5$ percent, $R_S = 0.1\Omega$ ; $t_r = t_f \leq 500 \text{ ns}$ ; $R_{BB1} = 50 \Omega$ ; $V_{BB1} = 10 \text{ V dc}$ ; $R_{BB2} = \infty$ ; $V_{BB2} = 0$ ; $V_{CC} \geq 20 \text{ V dc}$				
Test 1		$t_p = 375 \mu\text{s}$ (vary to obtain $I_C$ ); $I_C = 1 \text{ A dc}$ ; $L = 5 \text{ mH}$ (min) at 1 A with maximum dc resistance of $0.5 \Omega$ . For reference only: 2 ESSEX Stancor C-2688 (in parallel), or equivalent.				

See footnotes at end of table.

\* TABLE I. Group A inspection - Continued.

Inspection <u>1/</u>	MIL-STD-750		Symbol	Limits		Unit
	Method	Conditions		Min	Max	
<u>Subgroup 5</u> - Continued.						
Test 2		$t_p = 1.5$ ms (vary to obtain $I_C$ ); $I_C = .25$ A dc; L = 80 mH (min) at .25 A with a maximum dc resistance of 1 $\Omega$ . For reference only. ESSEX Stancor C-2691 or Triad C = 48				
SOA (clamped switching) (destructive)		$T_A = +25^\circ\text{C}$ ; $V_{CC} = 55$ V dc (see figures 11 and 12); duty cycle $\leq 5$ percent, $t_p = 1.5$ ms (vary to obtain $I_C$ ); $I_C = 4$ A dc				
2N3740, 2N3740U4 2N3741, 2N3741U4		Clamp voltage = 60 V dc Clamp voltage = 80 V dc				
End-point electrical measurements		See table I, subgroup 2 herein.				
<u>Subgroups 6 and 7</u>						
Not applicable						

- 1/ For sampling plan, see MIL-PRF-19500.  
2/ For resubmission of failed subgroup 1, double the sample size of the failed test or sequence of tests.  
3/ Separate samples may be used.  
4/ Not required for JANS.  
5/ Not required for laser marked devices.  
6/ This test required for the following end-point measurements only:  
Group B, subgroups 3, 4, and 5 (JANS).  
Group B, see 4.4.2.2 herein, after each step (JAN, JANTX, and JANTXV).  
Group C, subgroup 2 and 6 for JANS and subgroup 2 only for JAN, JANTX, and JANTXV.  
Group E, subgroup 1.

\* TABLE II. Group B, C, and E delta measurements. 1/ 2/ 3/ 4/

Step	Inspection (1) (2) (3) (4)	MIL-STD-750		Symbol	Limits		Unit
		Method	Conditions		Min	Max	
1.	Collector to emitter cutoff current  2N3740, 2N3740U4 2N3741, 2N3741U4	3041	Bias condition A; $V_{BE} = 1.5$ V dc  $V_{CE} = 60$ V dc $V_{CE} = 80$ V dc	$\Delta I_{CEX1}$			100 percent of initial value or 50 nA dc, whichever is greater.
2.	Forward-current transfer ratio	3076	$V_{CE} = 1$ V dc; $I_C = 250$ mA dc; pulsed (see 4.5.1)	$\Delta h_{FE2}$			$\pm 25$ percent change from initial reading.
3.	Saturation voltage and resistance	3071	$I_C = 250$ mA dc; $I_B = 25$ mA dc; pulsed (see 4.5.1)	$\Delta V_{CE(sat)1}$			50 mV dc change from initial value

- (1) The delta measurements for table E-VIA (JANS) of MIL-PRF-19500 are as follows:
  - a. Subgroup 4, see table II, step 3.
  - b. Subgroup 5, see table II, steps 1, 2, and 3.
- (2) The delta measurements for 4.4.2.2, group B (JAN, JANTX, and JANTXV) of MIL-PRF-19500 are after each step in 4.4.2.2, see table II, steps 1, 2, and 3.
- (3) The delta measurements for table E-VII of MIL-PRF-19500 are as follows: Subgroup 6, see table II, steps 1 and 2 (JANS only).
- (4) The delta measurements for table E-IX (all quality levels) of MIL-PRF-19500 are as follows: Subgroup 1, see table II, step 2; subgroup 2, see table II, steps 1 and 2.

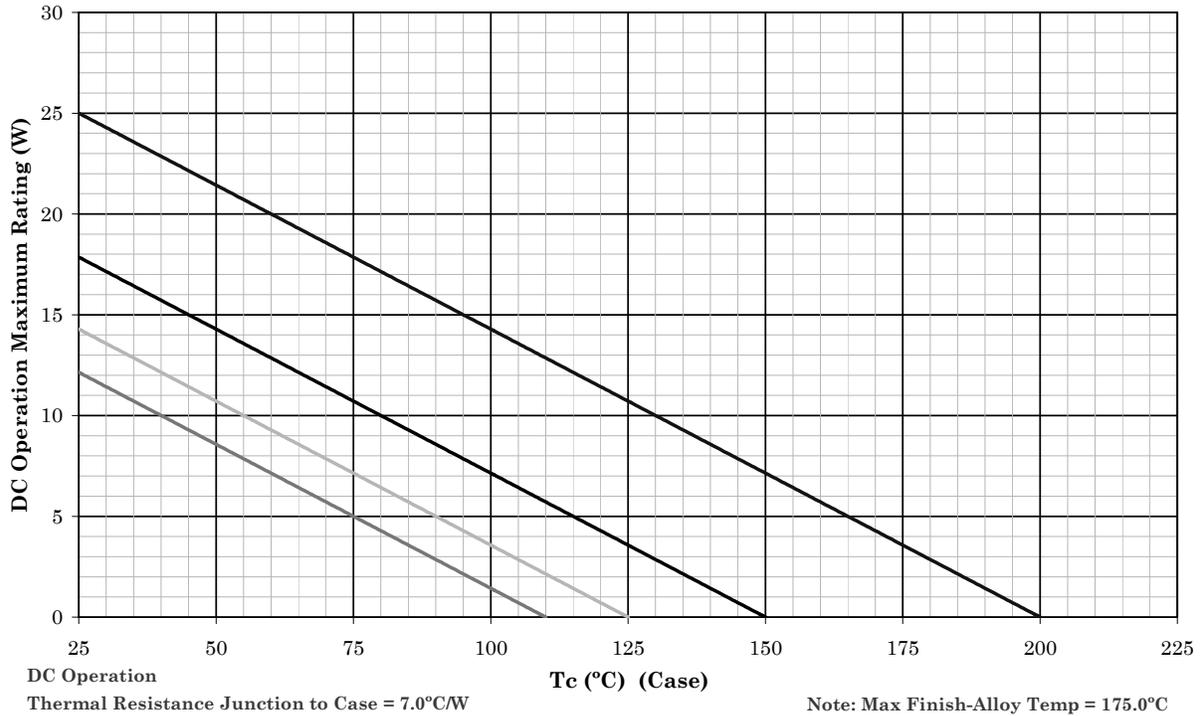
MIL-PRF-19500/441J

\* TABLE III. Group E inspection (all quality levels) - for qualification or re-qualification only.

Inspection	MIL-STD-750		Sample plan
	Method	Conditions	
<u>Subgroup 1</u>			45 devices c = 0
Temperature cycling (air to air)	1051	Test condition C, 500 cycles	
Hermetic seal Fine leak Gross leak	1071		
Electrical measurements		See table I, subgroup 2 and table II herein.	
<u>Subgroup 2</u>			45 devices c = 0
Blocking life	1048	T <sub>A</sub> = +150°C, V <sub>CB</sub> = 80 percent of rated voltage, t = 1,000 hours.	
Electrical measurements		See table I, subgroup 2 and table II herein.	
<u>Subgroup 4</u>			sample size N/A
Thermal impedance curves		See MIL-PRF-19500.	
<u>Subgroup 6</u>			3 devices
ESD	1020	Testing is not required for class 3 listing. Testing is required for a nonsensitive listing to prove capability.	
<u>Subgroup 8</u>			45 devices c = 0
Reverse stability	1033	Condition B.	

## Temperature-Power Derating Curve

2N3740, 2N3741



$$R_{\theta JC} = 7^{\circ}\text{C}/\text{W}$$

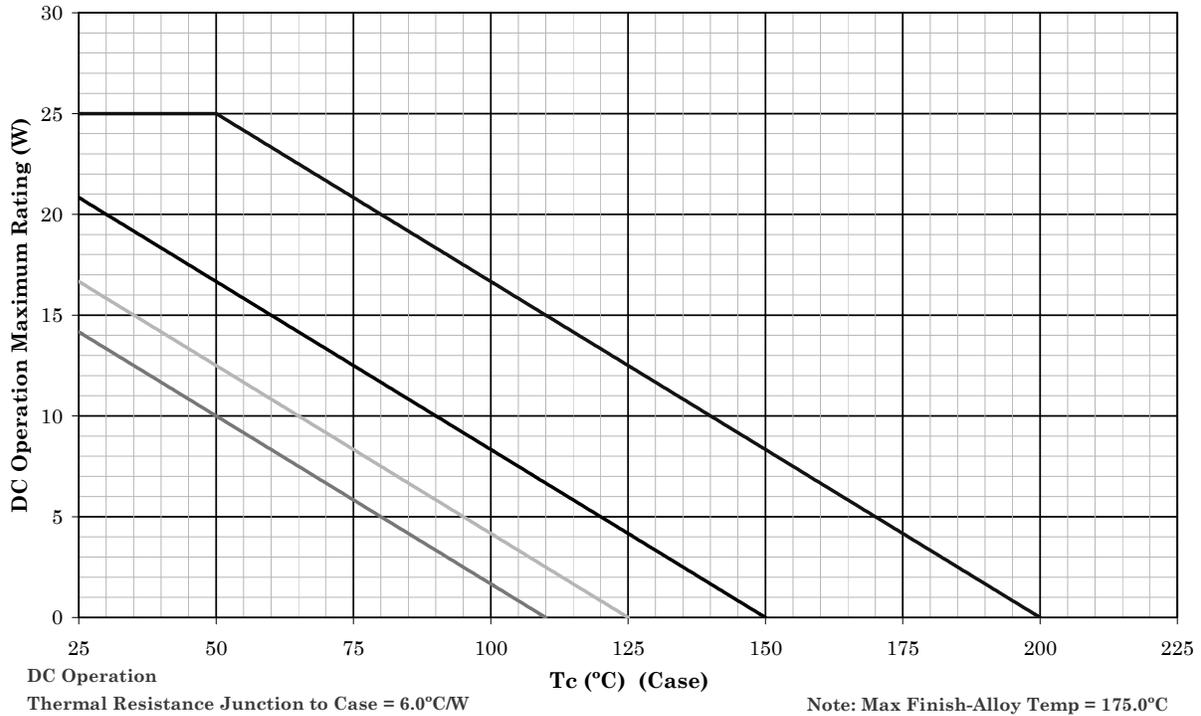
### NOTES:

1. All devices are capable of operating at  $\leq T_J$  specified on this curve. Any parallel line to this curve will intersect the appropriate power for the desired maximum  $T_J$  allowed.
2. Derate design curve constrained by the maximum junction temperature ( $T_J \leq +200^{\circ}\text{C}$ ) and power rating specified. (See 1.3 herein.)
3. Derate design curve chosen at  $T_J \leq +150^{\circ}\text{C}$  where the maximum temperature of electrical test is performed.
4. Derate design curves chosen at  $T_J \leq +125^{\circ}\text{C}$  and  $+110^{\circ}\text{C}$  to show power rating where most users want to limit  $T_J$  in their application.

\* FIGURE 5. Temperature-power derating graph (2N3740, 2N3741, TO-66).

### Temperature-Power Derating Curve

2N3740U4, 2N3741U4



$$R_{\theta JC} = 6^\circ\text{C/W}$$

NOTES:

1. All devices are capable of operating at  $\leq T_J$  specified on this curve. Any parallel line to this curve will intersect the appropriate power for the desired maximum  $T_J$  allowed.
2. Derate design curve constrained by the maximum junction temperature ( $T_J \leq +200^\circ\text{C}$ ) and power rating specified. (See 1.3 herein.)
3. Derate design curve chosen at  $T_J \leq +150^\circ\text{C}$  where the maximum temperature of electrical test is performed.
4. Derate design curves chosen at  $T_J \leq +125^\circ\text{C}$  and  $+110^\circ\text{C}$  to show power rating where most users want to limit  $T_J$  in their application.

\* FIGURE 6. Temperature-power derating graph (2N3740U4, 2N3741U4).

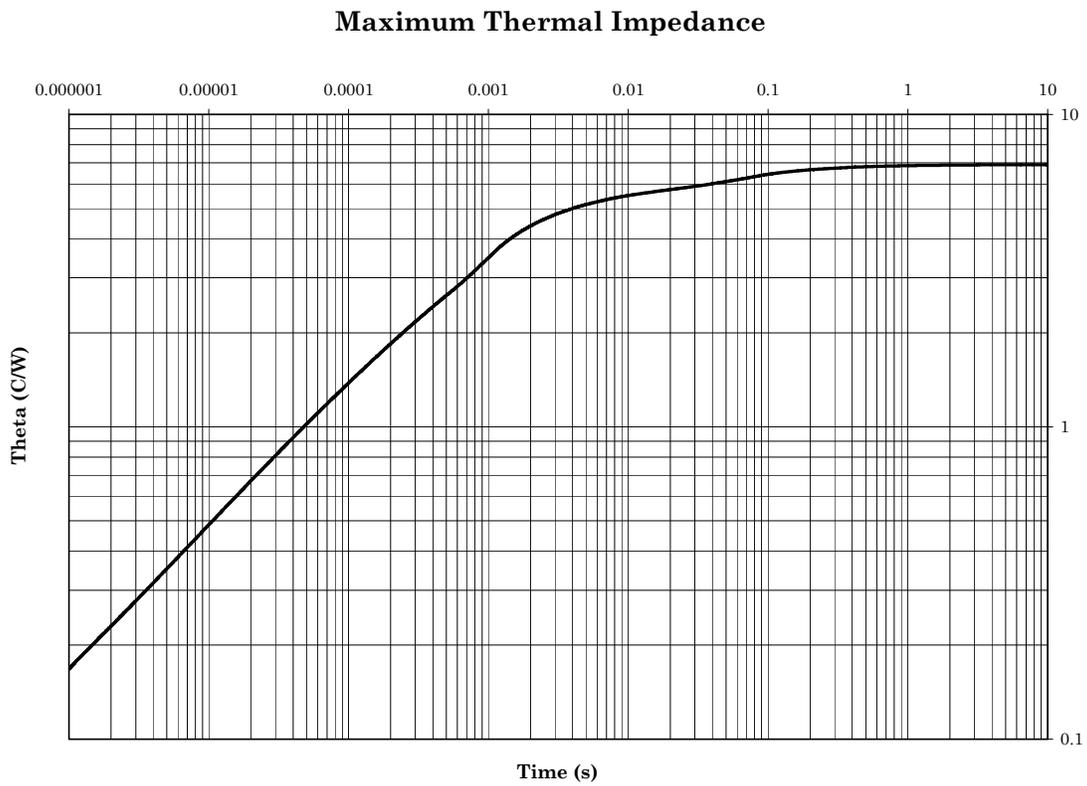


FIGURE 7. Transient thermal impedance graph (2N3740 and 2N3741).

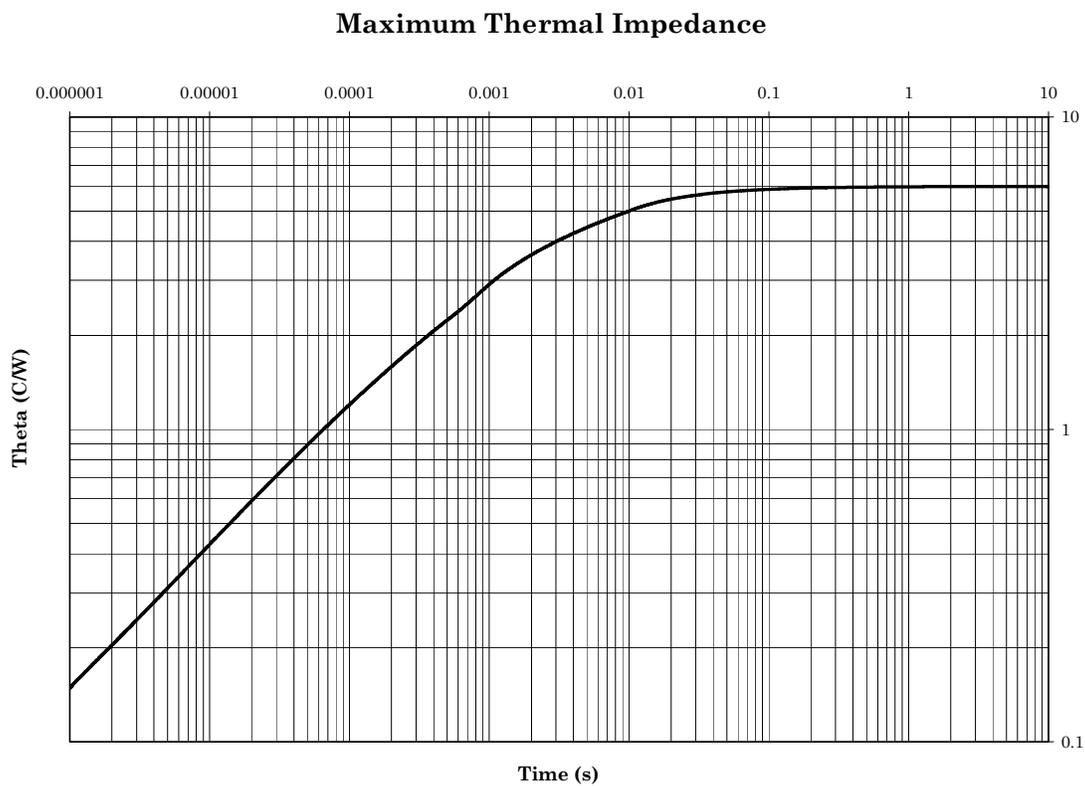
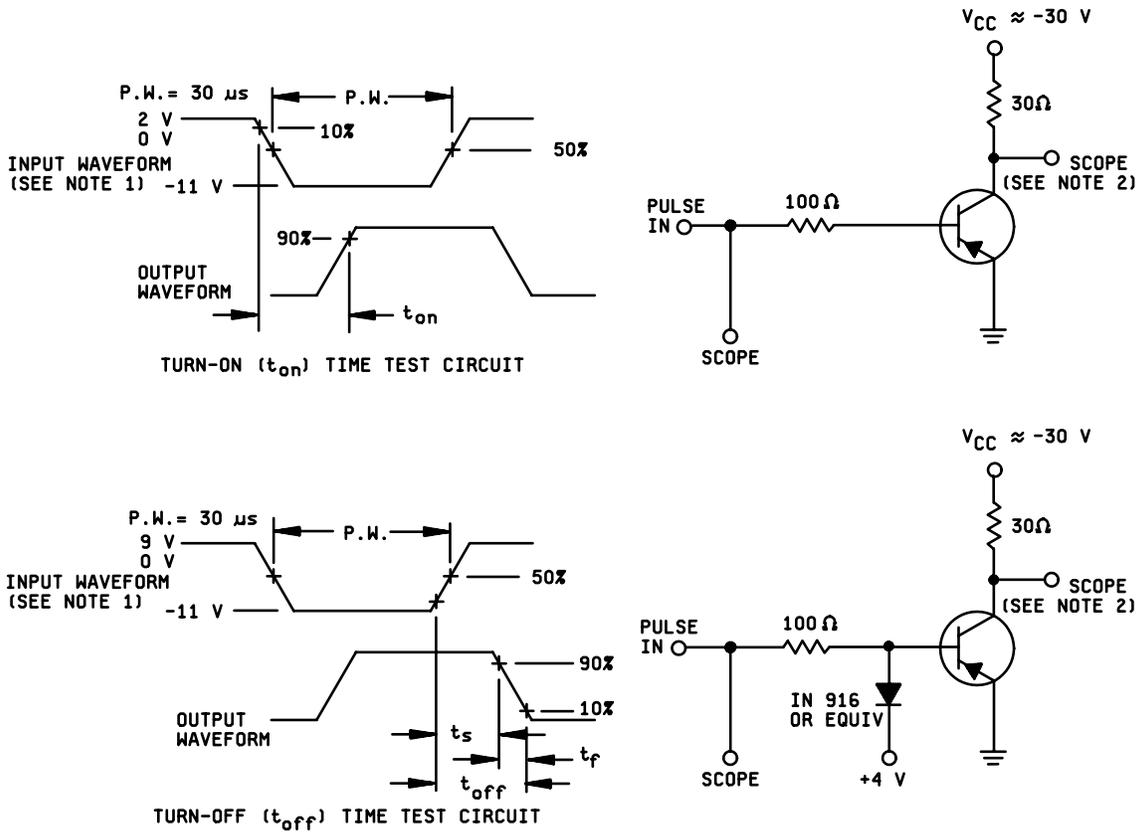


FIGURE 8. Transient thermal impedance graph (2N3740U4 and 2N3741U4).



NOTES:

1. The rise time ( $t_r$ ) of the applied pulse shall be  $\leq 20$  ns; duty cycle  $\leq 2$  percent; generator source impedance shall be  $50 \Omega$ .
2. Output sampling oscilloscope:  $Z_{in} \geq 100$  k $\Omega$ ;  $C_{in} \leq 12$  pF; rise time  $\leq 2$  ns.

FIGURE 9. Pulse response test circuits.

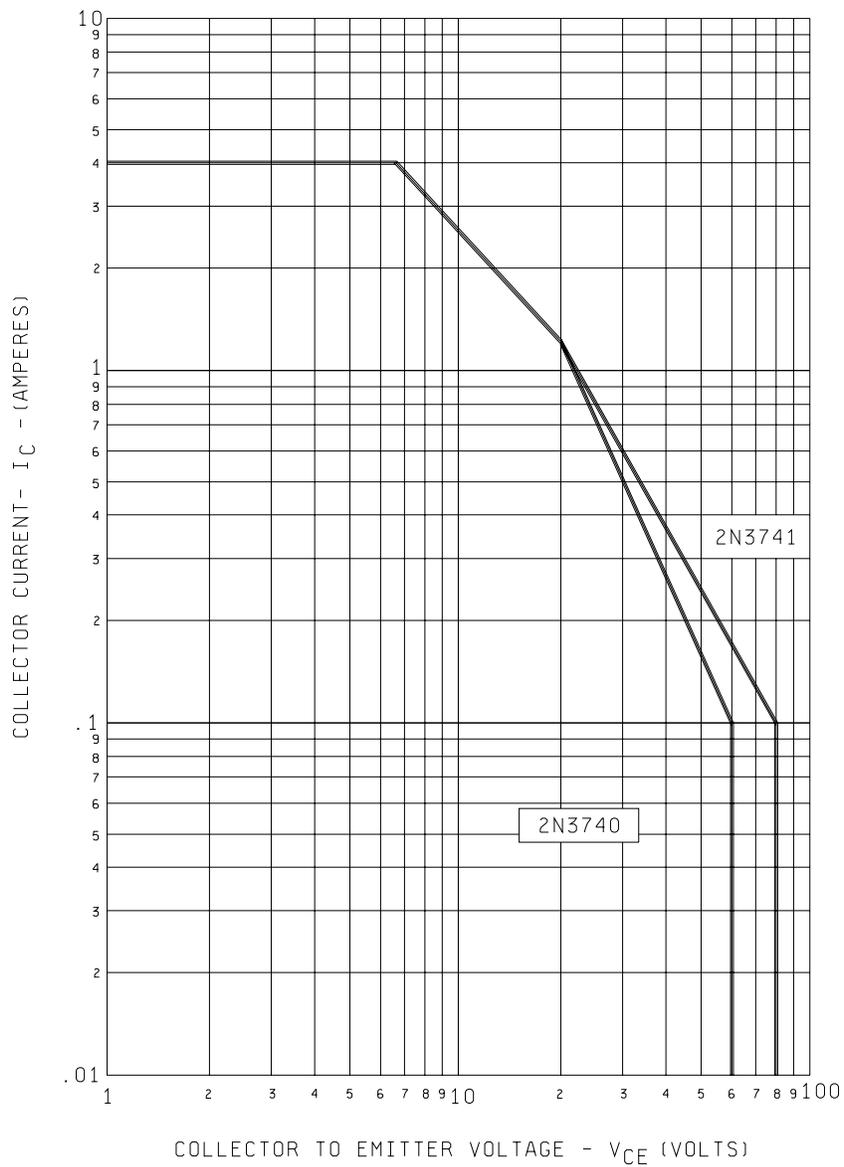
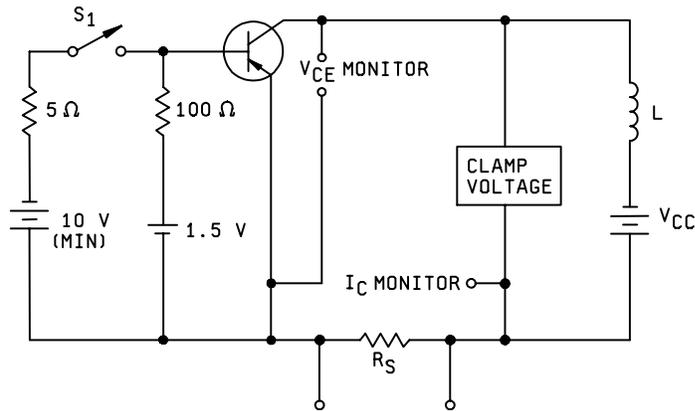


FIGURE 10. Maximum SOA graph (continuous dc, all devices).



$R_S \leq .1\Omega$  12W; 1 percent tolerance maximum (noninductive).

$L = 5$  mH at 4 A with a maximum dc resistance of 0.5  $\Omega$ .  
Reference only: 2 ESSEX Stancor C-2688 (in parallel), or equivalent.

Procedure

1. With switch  $S_1$  closed, set the specified test conditions.
2. Open  $S_1$ . Device fails if the clamp voltage is not reached.
3. Perform specified end-point tests.

FIGURE 11. Clamped inductive sweep test circuit.

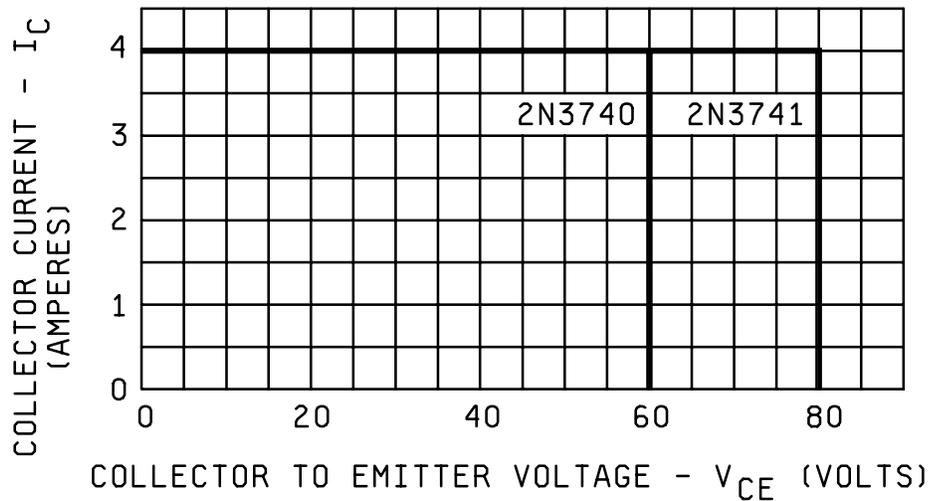


FIGURE 12. SOA for switching between saturation and cutoff (clamped inductive load, all devices).

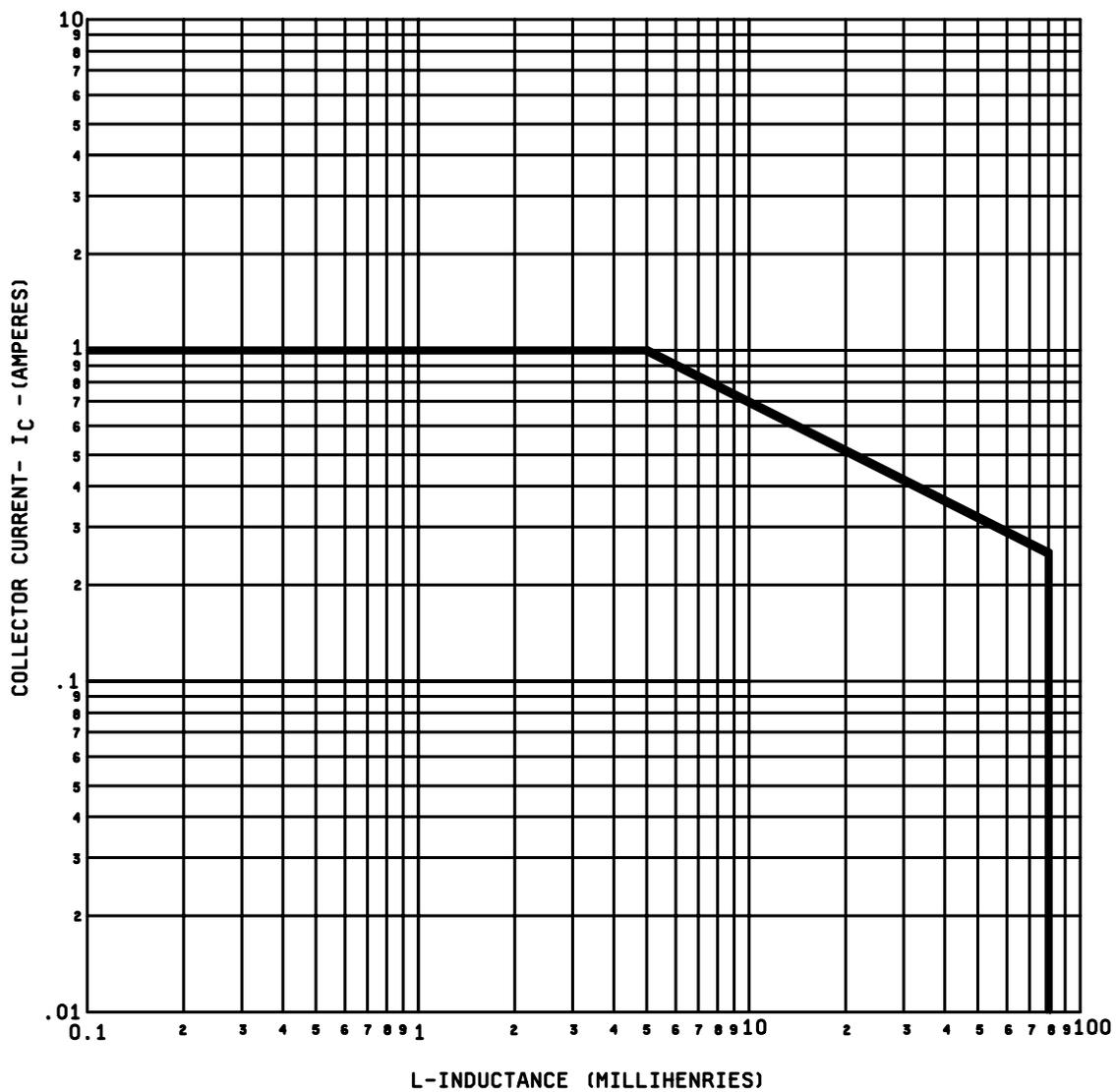


FIGURE 13. Safe operating area for switching between saturation and cutoff (unclamped inductive load).

5. PACKAGING

\* 5.1 Packaging. For acquisition purposes, the packaging requirements shall be as specified in the contract or order (see 6.2). When packaging of materiel is to be performed by DoD or in-house contractor personnel, these personnel need to contact the responsible packaging activity to ascertain packaging requirements. Packaging requirements are maintained by the Inventory Control Point's packaging activities within the Military Service or Defense Agency, or within the Military Service's system commands. Packaging data retrieval is available from the managing Military Department's or Defense Agency's automated packaging files, CD-ROM products, or by contacting the responsible packaging activity.

6. NOTES

(This section contains information of a general or explanatory nature that may be helpful, but is not mandatory.)

6.1 Intended use. The notes specified in MIL-PRF-19500 are applicable to this specification.

\* 6.2 Acquisition requirements. Acquisition documents should specify the following:

- a. Title, number, and date of this specification.
- b. Packaging requirements (see 5.1).
- c. Lead finish (see 3.4.1).
- d. Product assurance level and type designator.

\* 6.3 Qualification. With respect to products requiring qualification, awards will be made only for products which are, at the time of award of contract, qualified for inclusion in Qualified Manufacturers List (QML 19500) whether or not such products have actually been so listed by that date. The attention of the contractors is called to these requirements, and manufacturers are urged to arrange to have the products that they propose to offer to the Federal Government tested for qualification in order that they may be eligible to be awarded contracts or orders for the products covered by this specification. Information pertaining to qualification of products may be obtained from Defense Supply Center, Columbus, ATTN: DSCC/VQE, P.O. Box 3990, Columbus, OH 43218-3990 or e-mail [vqe.chief@dla.mil](mailto:vqe.chief@dla.mil).

6.4. Suppliers of JANHC and JANKC die. The qualified JANHC and JANKC suppliers with the applicable letter version (example, JANHCA3740) will be identified on the QML.

JANC ordering information		
PIN	Manufacturer	
	33178	43611
2N3740	JANHCA2N3740	JANHCB2N3740
2N3740	JANKCA2N3740	JANKCB2N3740
2N3741	JANHCA2N3741	JANHCB2N3741
2N3741	JANKCA2N3741	JANKCB2N3741

6.5 Changes from previous issue. The margins of this specification are marked with asterisks to indicate where changes from the previous issue were made. This was done as a convenience only and the Government assumes no liability whatsoever for any inaccuracies in these notations. Bidders and contractors are cautioned to evaluate the requirements of this document based on the entire content irrespective of the marginal notations and relationship to the last previous issue.

Custodians:

Army - CR  
Navy - EC  
Air Force - 11  
NASA - NA  
DLA - CC

Preparing activity:  
DLA - CC

(Project 5961-3029)

Review activities:

Army - AR, AV, MI, SM  
Navy - AS, MC  
Air Force - 19, 71, 99

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